

**ORDERING INFORMATION**

TEMP. RANGE	CONFIGURATION	PACKAGE	PART NUMBER	MIN. ORDER / PACK. QUANTITY
-40 °C to +85 °C Lead (Pb)-free	DG441LE	16-pin TSSOP	DG441LEDQ-GE3	Tube 360 units
			DG441LEDQ-T1-GE3	Tape and reel, 3000 units
		16-pin SOIC	DG441LEDY-GE3	Tube 500 units
			DG441LEDY-T1-GE3	Tape and reel, 2500 units
		16-pin PDIP	DG441LEDJ-GE3	Tube 500 units
	DG442LE	16-pin TSSOP	DG442LEDQ-GE3	Tube 360 units
			DG442LEDQ-T1-GE3	Tape and reel, 3000 units
		16-pin SOIC	DG442LEDY-GE3	Tube 500 units
			DG442LEDY-T1-GE3	Tape and reel, 2500 units
		16-pin PDIP	DG442LEDJ-GE3	Tube 500 units

ABSOLUTE MAXIMUM RATINGS ($T_A = 25\text{ °C}$, unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT
V+ to V-		-0.3 to +18	V
GND to V _A		18	
Digital Inputs ^a V _S , V _D		GND -0.3 to (V+) + 0.3 or 30 mA, whichever occurs first	
Continuous Current (any terminal)		30	mA
Current, S or D (pulsed 1 ms, 10 % duty cycle)		100	
Storage Temperature	(DQ, DY suffix)	-65 to +125	°C
	(AK suffix)	-65 to +150	
Power Dissipation (packages) ^b	16-pin TSSOP ^c	450	mW
	16-pin narrow body SOIC ^d	650	
	16-pin CerDIP ^e	900	
ESD Human Body Model (HBM); per ANSI / ESDA / JEDEC® JS-001		2500	V
Latch Up Current, per JESD78D		400	mA

Notes

- a. Signals on S_X, D_X, or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 7 mW/°C above 75 °C.
- d. Derate 7.6 mW/°C above 75 °C.
- e. Derate 12 mW/°C above 75 °C.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



SPECIFICATIONS ^a (single supply 12 V)									
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V ₊ = 12 V, V ₋ = 0 V V _{IN} = 2.4 V, 0.8 V ^f	TEMP. ^b	TYP. ^c	A SUFFIX LIMITS -55 °C to +125 °C		D SUFFIX LIMITS -40 °C to +85 °C		UNIT
					MIN. ^d	MAX. ^d	MIN. ^d	MAX. ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full	-	0	12	0	12	V
Drain-Source On-Resistance	R _{DS(on)}	V ₊ = 10.8 V, V ₋ = 0 V I _S = 10 mA, V _D = 2 V / 9 V	Room	16	-	26	-	26	Ω
			Full	-	-	40	-	35	
On-Resistance Match Between Channels ^e	ΔR _{DS(on)}	I _S = 10 mA, V _D = 9 V	Room	0.1	-	0.5	-	0.5	
Switch Off Leakage Current	I _{S(off)}	V _D = 1 V / 11 V, V _S = 11 V / 1 V	Room	-	-1	1	-1	1	nA
	I _{D(off)}		Full	-	-15	15	-10	10	
			Room	-	-1	1	-1	1	
			Full	-	-15	15	-10	10	
Channel On Leakage Current	I _{D(on)}	V _S = V _D = 11 V / 1 V	Room	-	-1	1	-1	1	
			Full	-	-15	15	-10	10	
Digital Control									
Input Current, V _{IN} Low	I _{IL}	V _{IN} under test = 0.8 V	Full	0.01	-1.5	1.5	-1	1	μA
Input Current, V _{IN} High	I _{IH}	V _{IN} under test = 2.4 V	Full	-	-1.5	1.5	-1	1	
Dynamic Characteristics									
Turn-On Time	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _S = 5 V, see figure 2	Room	18	-	60	-	60	ns
			Full	-	-	80	-	70	
Turn-Off Time	t _{OFF}		Room	18	-	35	-	35	
			Full	-	-	50	-	45	
Charge Injection ^e	Q	V _g = 0 V, R _g = 0 Ω, C _L = 10 nF	Room	6.6	-	-	-	-	pC
Off Isolation ^e	OIRR	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz	Room	68.4	-	-	-	-	dB
Channel-to-Channel Crosstalk ^e	X _{TALK}		Room	114	-	-	-	-	
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz	Room	5	-	-	-	-	pF
Drain Off Capacitance ^e	C _{D(off)}		Room	6	-	-	-	-	
Channel On Capacitance ^e	C _{D(on)}		Room	15	-	-	-	-	
Power Supplies									
Positive Supply Current	I ₊	V _{IN} = 0 V or 12 V	Full	0.03	-	1.5	-	1	μA
Negative Supply Current	I ₋		Room	-	-1	-	-1	-	
			Full	0.002	-7.5	-	-5	-	
Ground Current	I _{GND}		Full	0.002	-1.5	-	-1	-	



SPECIFICATIONS ^a (dual supply ± 5 V)									
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED $V_+ = 5$ V, $V_- = -5$ V $V_{IN} = 2.4$ V, 0.8 V ^f	TEMP. ^b	TYP. ^c	A SUFFIX LIMITS -55 °C to +125 °C		D SUFFIX LIMITS -40 °C to +85 °C		UNIT
					MIN. ^d	MAX. ^d	MIN. ^d	MAX. ^d	
Analog Switch									
Analog Signal Range ^e	V_{ANALOG}		Full	-	-5	5	-5	5	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_+ = 5$ V, $V_- = -5$ V $I_S = 10$ mA, $V_D = \pm 3.5$ V	Room	18	-	30	-	30	Ω
			Full	-	-	42	-	37	
On-Resistance Match Between Channels ^e	$\Delta R_{DS(on)}$	$I_S = 10$ mA, $V_D = \pm 3.5$ V	Room	0.1	-	0.5	-	0.5	
Switch Off Leakage Current ^g	$I_{S(off)}$	$V_+ = 5.5$, $V_- = -5.5$ V $V_D = \pm 4.5$ V, $V_S = \pm 4.5$ V	Room	-	-1	1	-1	1	nA
			Full	-	-15	15	-10	10	
	$I_{D(off)}$		Room	-	-1	1	-1	1	
			Full	-	-15	15	-10	10	
Channel On Leakage Current ^g	$I_{D(on)}$	$V_+ = 5.5$ V, $V_- = -5.5$ V $V_S = V_D = \pm 4.5$ V	Room	-	-1	1	-1	1	
			Full	-	-15	15	-10	10	
Digital Control									
Input Current, V_{IN} Low ^e	I_{IL}	V_{IN} under test = 0.8 V	Full	0.05	-1.5	1.5	-1	1	μ A
Input Current, V_{IN} High ^e	I_{IH}	V_{IN} under test = 2.4 V	Full	0.05	-1.5	1.5	-1	1	
Dynamic Characteristics									
Turn-On Time	t_{ON}	$R_L = 300 \Omega$, $C_L = 35$ pF $V_S = \pm 3.5$ V, see figure 2	Room	42	-	65	-	65	ns
			Full	-	-	90	-	75	
Turn-Off Time	t_{OFF}		Room	34	-	45	-	45	
			Full	-	-	65	-	55	
Charge Injection ^e	Q	$V_g = 0$ V, $R_g = 0 \Omega$, $C_L = 10$ nF	Room	5.8	-	-	-	-	pC
Off Isolation ^e	OIRR	$R_L = 50 \Omega$, $C_L = 5$ pF, $f = 1$ MHz	Room	68.4	-	-	-	-	dB
Channel-to-Channel Crosstalk ^e	X_{TALK}		Room	113	-	-	-	-	
Source Off Capacitance ^e	$C_{S(off)}$	f = 1 MHz	Room	5	-	-	-	-	pF
Drain Off Capacitance ^e	$C_{D(off)}$		Room	6	-	-	-	-	
Channel On Capacitance ^e	$C_{D(on)}$		Room	14	-	-	-	-	
Power Supplies									
Positive Supply Current ^e	I +	$V_{IN} = 0$ V or 5 V	Full	0.002	-	1.5	-	1	μ A
Negative Supply Current ^e	I -		Room	-0.002	-1	-	-1	-	
			Full	-	-7.5	-	-5	-	
Ground Current ^e	I_{GND}		Full	-0.002	-1.5	-	-1	-	



SPECIFICATIONS ^a (single supply ± 5 V)									
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V ₊ = 5 V, V ₋ = 0 V V _{IN} = 2.4 V, 0.8 V ^f	TEMP. ^b	TYP. ^c	A SUFFIX LIMITS -55 °C to +125 °C		D SUFFIX LIMITS -40 °C to +85 °C		UNIT
					MIN. ^d	MAX. ^d	MIN. ^d	MAX. ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full	-	-	5	-	5	V
Drain-Source On-Resistance ^e	R _{DS(on)}	V ₊ = 4.5 V I _S = 5 mA, V _D = 1 V, 3.5 V	Room	36	-	50	-	50	Ω
			Full	-	-	88	-	75	
On-Resistance Match Between Channels ^e	ΔR _{DS(on)}	I _S = 10 mA, V _D = 3.5 V	Room	0.5	-	1	-	1	
Dynamic Characteristics									
Turn-On Time ^e	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _S = 3.5 V, see figure 2	Room	53	-	70	-	70	ns
			Hot	-	-	90	-	80	
Turn-Off Time ^e	t _{OFF}		Room	34	-	50	-	50	
			Hot	-	-	70	-	60	
Charge Injection ^e	Q	V _g = 0 V, R _g = 0 Ω, C _L = 10 nF	Room	3.3	-	-	-	-	pC
Power Supplies									
Positive Supply Current ^e	I ₊	V _{IN} = 0 V or 5 V	Full	10	-	200	-	100	μA
Negative Supply Current ^e	I ₋		Room	-0.002	-1	-	-1	-	
			Full	-	-7.5	-	-5	-	
Ground Current ^e	I _{GND}		Full	-10	-200	-	-100	-	



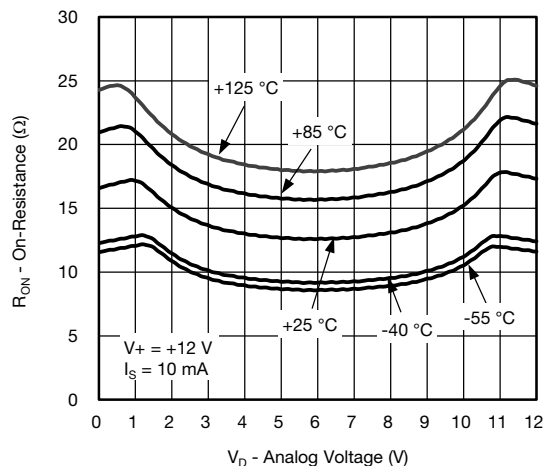
SPECIFICATIONS ^a (single supply 3 V)									
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V ₊ = 3 V, V ₋ = 0 V V _{IN} = 0.4 V ^f	TEMP. ^b	TYP. ^c	A SUFFIX LIMITS -55 °C to +125 °C		D SUFFIX LIMITS -40 °C to +85 °C		UNIT
					MIN. ^d	MAX. ^d	MIN. ^d	MAX. ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full	-	0	3	0	3	V
Drain-Source On-Resistance	R _{DS(on)}	V ₊ = 2.7 V, V ₋ = 0 V I _S = 5 mA, V _D = 0.5 V, 2.2 V	Room	106	-	130	-	130	Ω
			Full	-	-	150	-	140	
On-Resistance Match Between Channels ^e	ΔR _{DS(on)}	I _S = 5 mA, V _D = 2.2 V	Room	1	-	3	-	3	
Switch Off Leakage Current ^g	I _{S(off)}	V ₊ = 3.3, V ₋ = 0 V V _D = 1 V, 2 V, V _S = 2 V, 1 V	Room	-	-1	1	-1	1	nA
			Full	-	-15	15	-10	10	
	I _{D(off)}		Room	-	-1	1	-1	1	
			Full	-	-15	15	-10	10	
Channel On Leakage Current ^g	I _{D(on)}	V ₊ = 3.3 V, V ₋ = 0 V V _S = V _D = 1 V, 2 V	Room	-	-1	1	-1	1	
			Full	-	-15	15	-10	10	
Digital Control									
Input Current, V _{IN} Low ^e	I _{IL}	V _{IN} under test = 0.4 V	Full	0.005	-1.5	1.5	-1	1	μA
Input Current, V _{IN} High ^e	I _{IH}	V _{IN} under test = 2.4 V	Full	0.005	-1.5	1.5	-1	1	
Dynamic Characteristics									
Turn-On Time	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _S = 1.5 V, see figure 2	Room	141	-	200	-	200	ns
			Full	-	-	220	-	210	
Turn-Off Time	t _{OFF}		Room	84	-	120	-	120	
			Full	-	-	140	-	130	
Charge Injection ^e	Q	V _g = 0 V, R _g = 0 Ω, C _L = 10 nF	Room	2	-	-	-	-	pC
Off Isolation ^e	OIRR	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz	Room	68	-	-	-	-	dB
Channel-to-Channel Crosstalk ^e	X _{TALK}		Room	107	-	-	-	-	
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz	Room	6	-	-	-	-	pF
Drain Off Capacitance ^e	C _{D(off)}		Room	7	-	-	-	-	
Channel On Capacitance ^e	C _{D(on)}		Room	15	-	-	-	-	

Notes

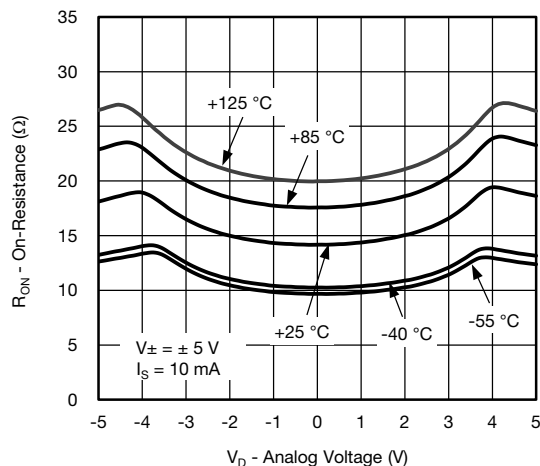
- Refer to PROCESS OPTION FLOWCHART.
- Room = 25 °C, full = as determined by the operating temperature suffix.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- Guaranteed by design, not subject to production test.
- V_{IN} = input voltage to perform proper function.
- Leakage parameters are guaranteed by worst case test conditions and not subject to test.



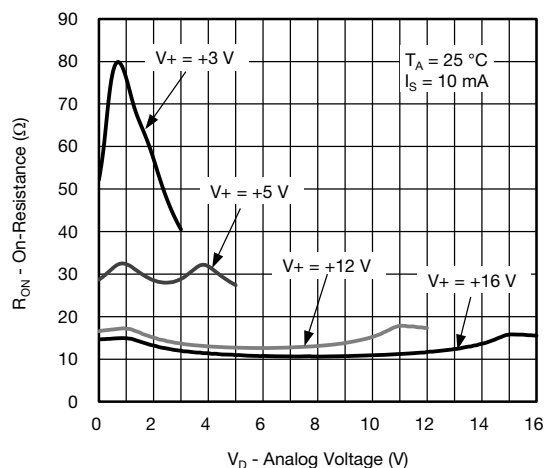
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



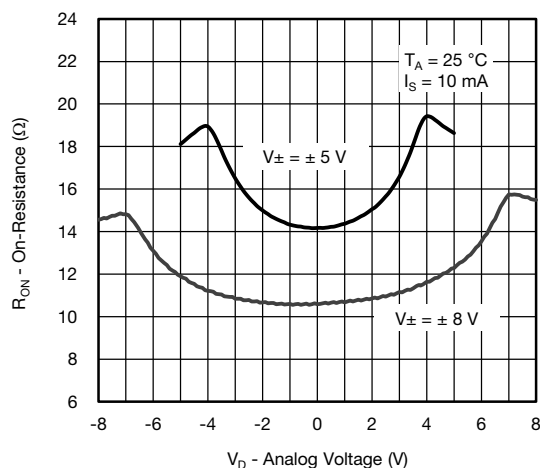
R_{DS(on)} vs. Analog Voltage and Temperature



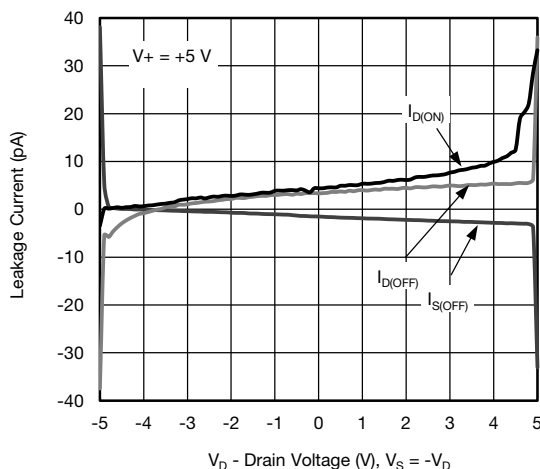
R_{DS(on)} vs. Drain Voltage and Temperature



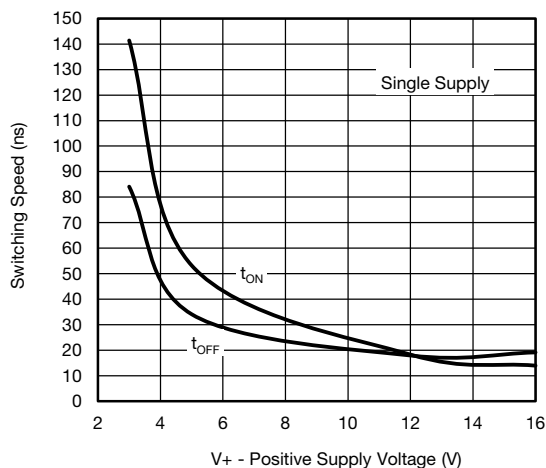
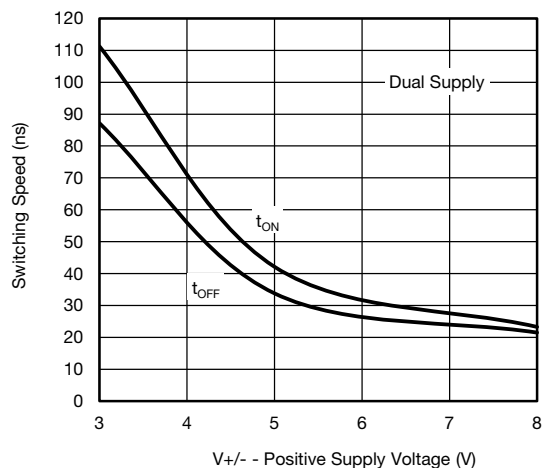
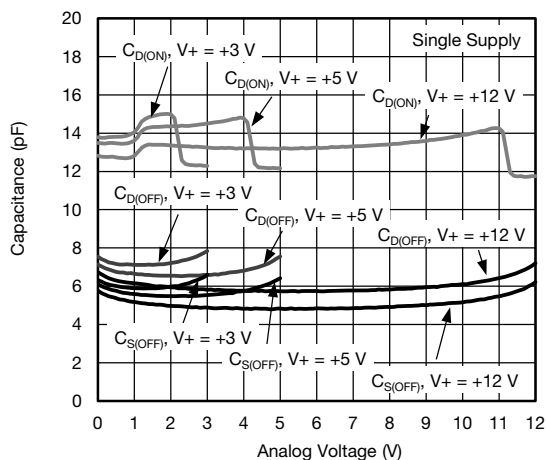
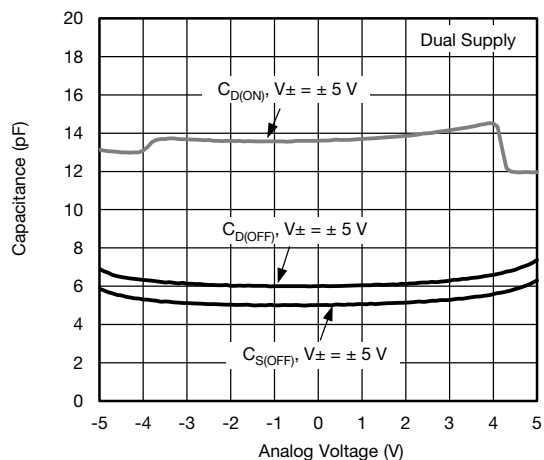
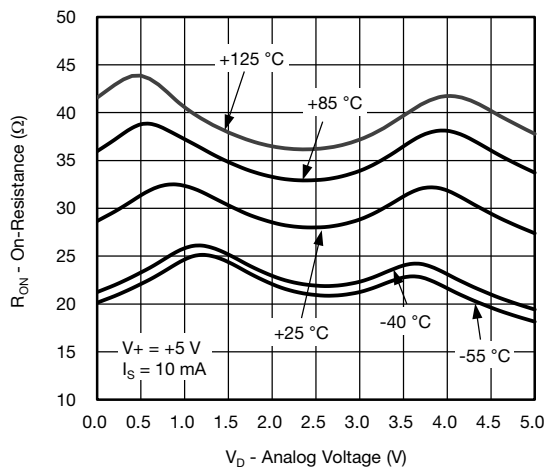
R_{DS(on)} vs. Analog Voltage

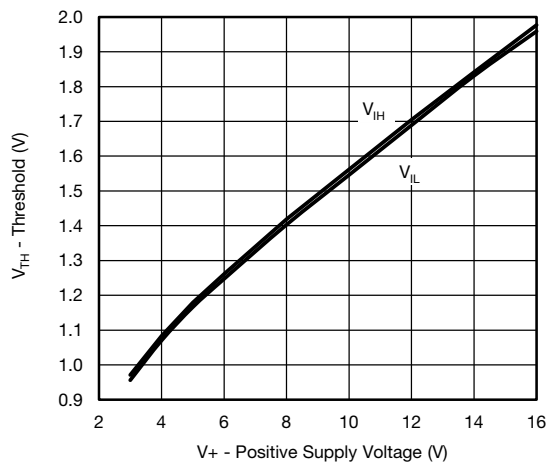
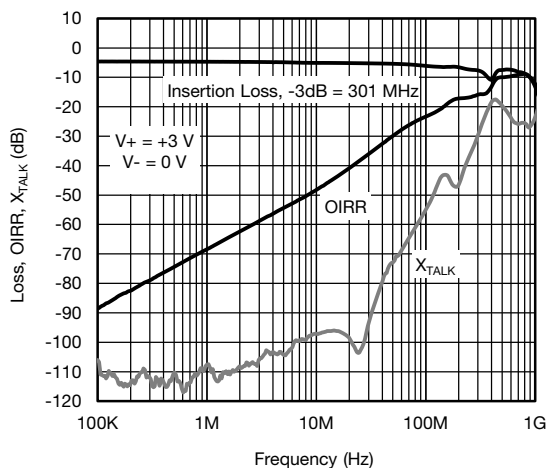
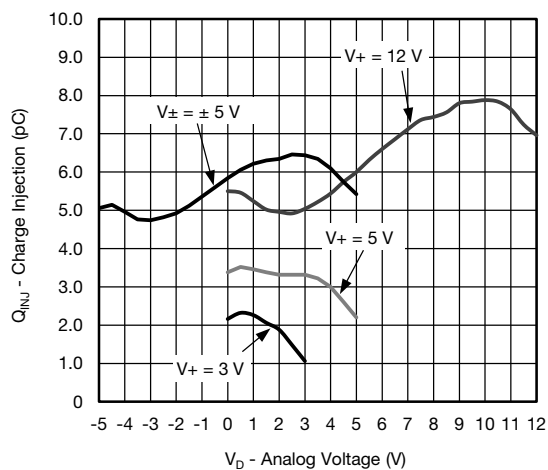
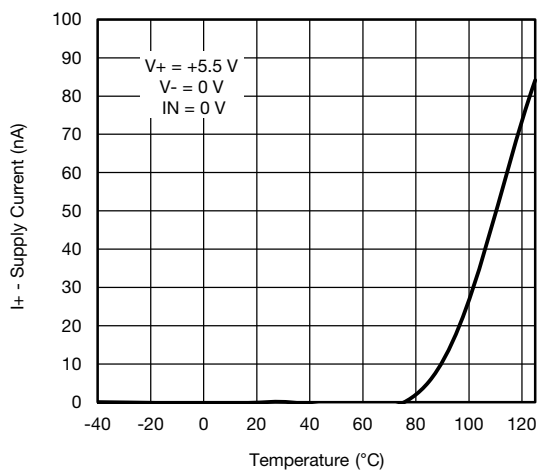


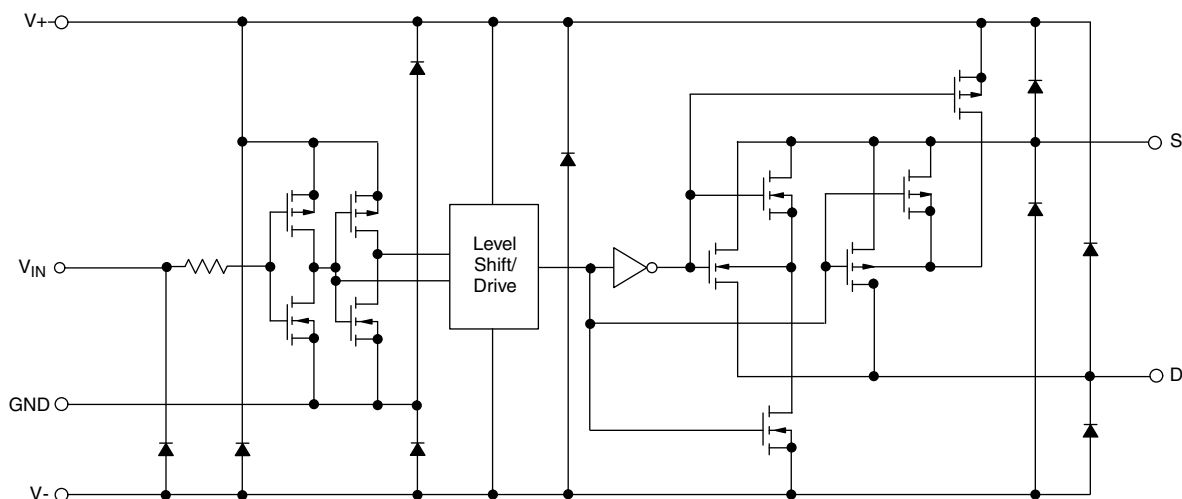
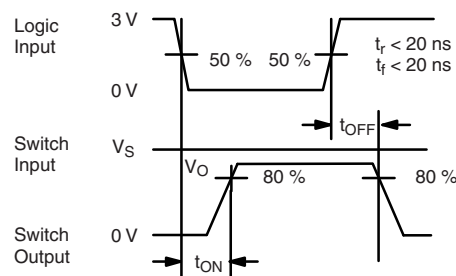
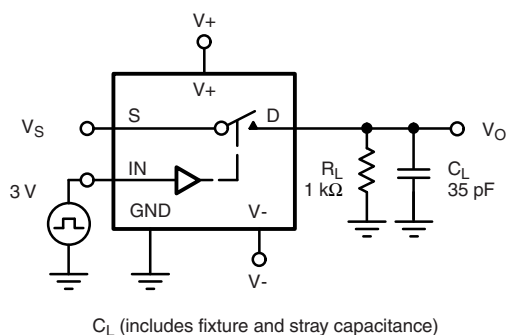
R_{DS(on)} vs. Analog Voltage



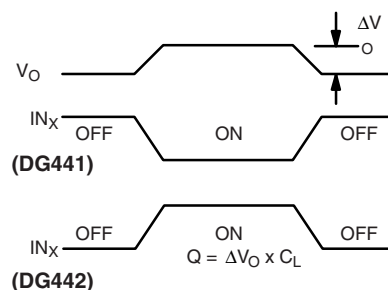
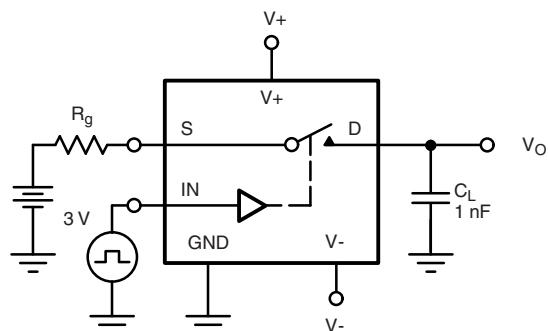
**Leakage Current vs. Drain Voltage
(Dual Supply)**

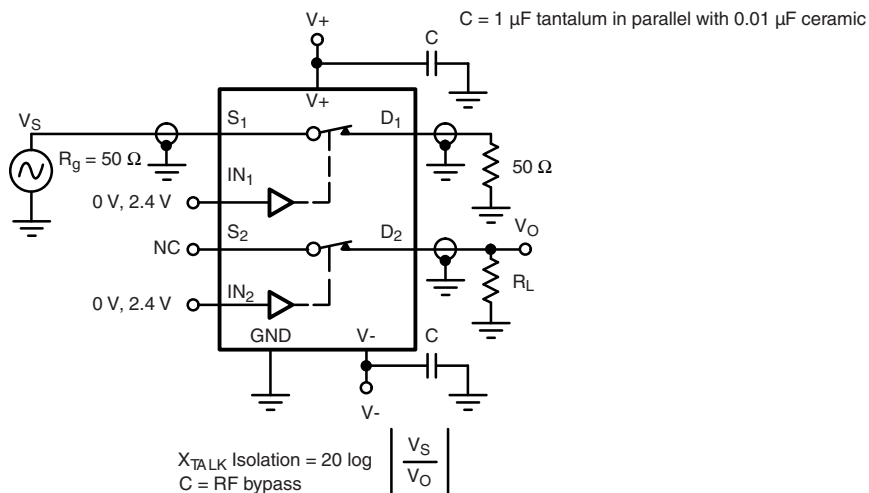
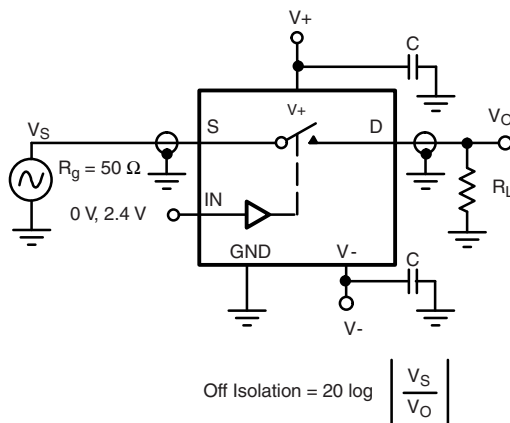
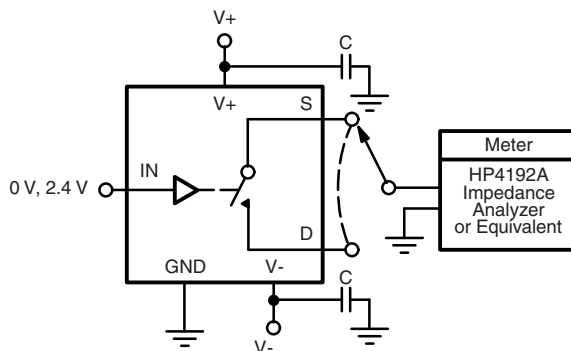
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Switching Time vs. Single Supply

Switching Time vs. Dual Supply

Capacitance vs. Analog Voltage (Single Supply)

Capacitance vs. Analog Voltage (Dual Supply)

R_{DS(on)} vs. Analog Voltage and Temperature

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Input Threshold vs. Single Supply Voltage

Insertion Loss, Off Isolation and Crosstalk vs. Frequency (Single Supply)

Charge Injection vs. Analog Voltage

Supply Current vs. Temperature

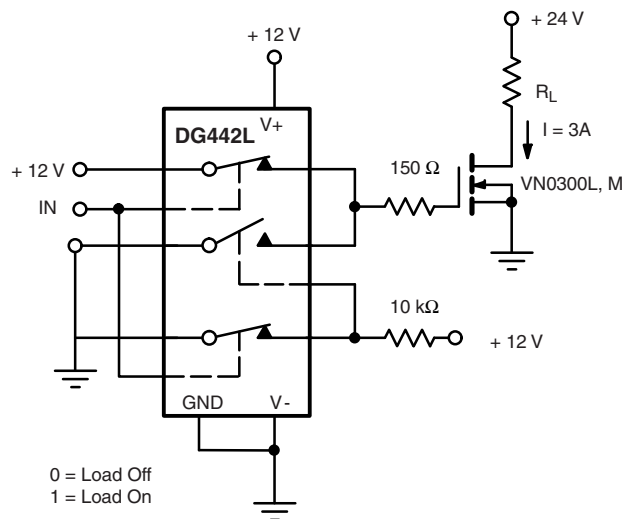
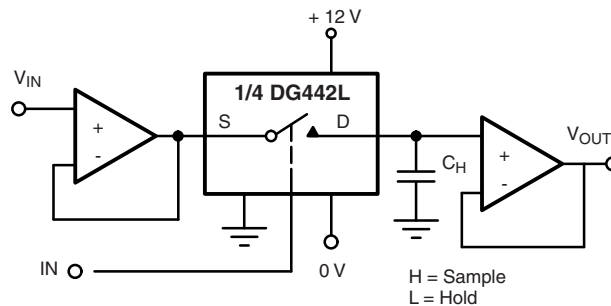
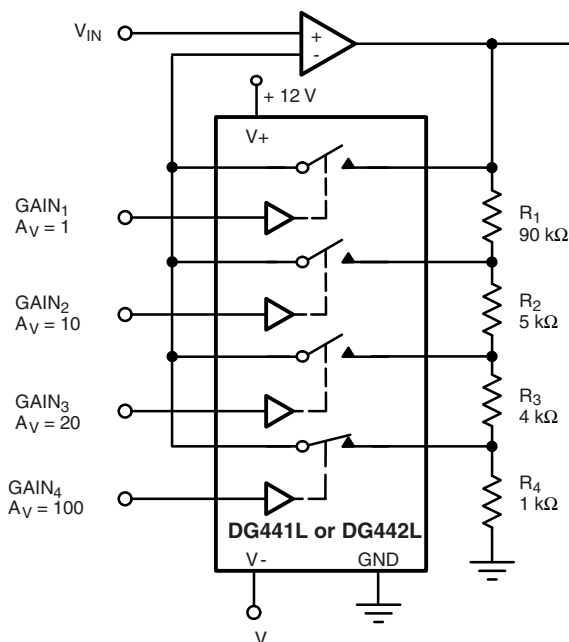
SCHEMATIC DIAGRAM (typical channel)

Fig. 1
TEST CIRCUITS


Note: Logic input waveform is inverted for DG442.

Fig. 2 - Switching Time

Fig. 3 - Charge Injection

TEST CIRCUITS

Fig. 4 - Crosstalk

Fig. 5 - Off Isolation

Fig. 6 - Source / Drain Capacitances

APPLICATIONS


Fig. 7 - Power MOSFET Driver

Fig. 8 - Open Loop Sample-and-Hold


Gain error is determined only by the resistor tolerance. Op amp offset and CMRR will limit accuracy of circuit.

With SW₄ Closed

$$\frac{V_{OUT}}{V_{IN}} = \frac{R_1 + R_2 + R_3 + R_4}{R_4} = 100$$

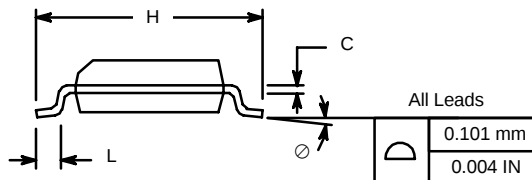
Fig. 9 - Precision-Weighted Resistor Programmable-Gain Amplifier

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?76754.



SOIC (NARROW): 16-LEAD

JEDEC Part Number: MS-012



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A ₁	0.10	0.20	0.004	0.008
B	0.38	0.51	0.015	0.020
C	0.18	0.23	0.007	0.009
D	9.80	10.00	0.385	0.393
E	3.80	4.00	0.149	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
L	0.50	0.93	0.020	0.037
Ø	0°	8°	0°	8°

ECN: S-03946—Rev. F, 09-Jul-01
DWG: 5300



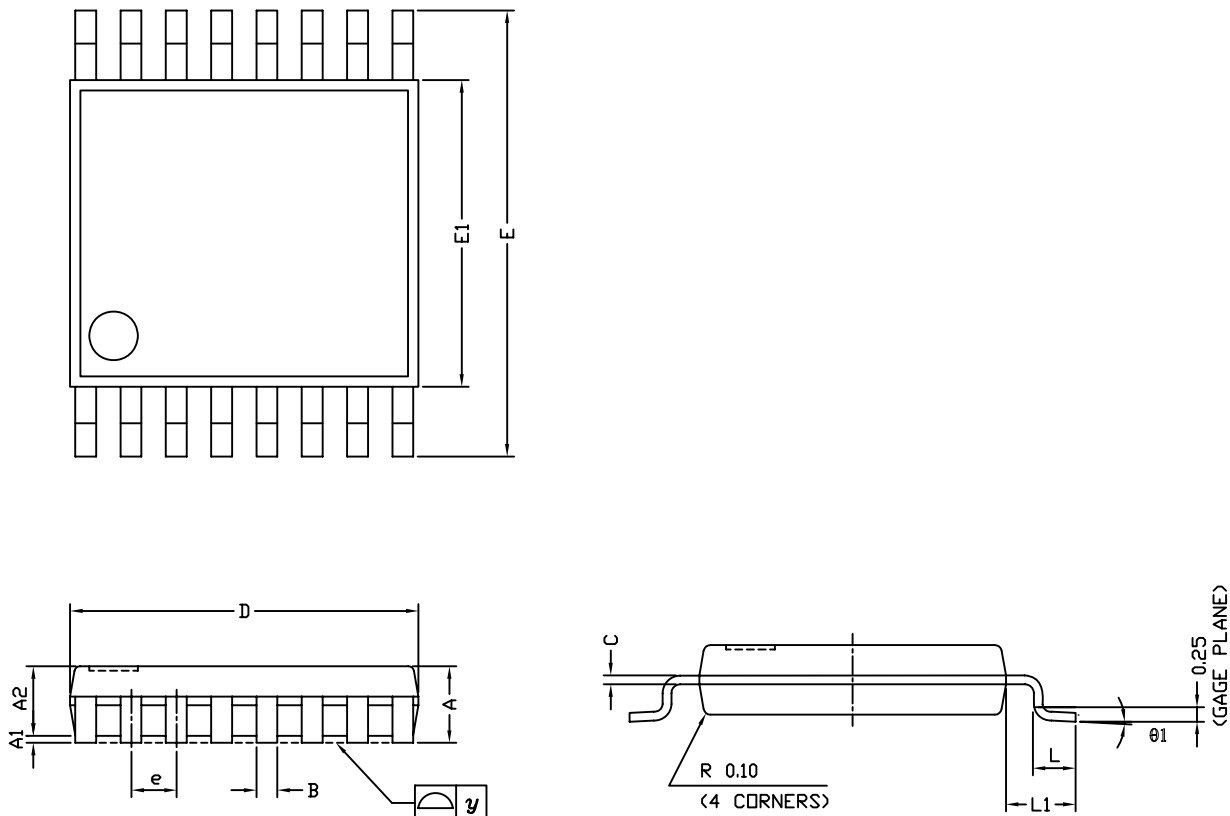
PDIP: 16-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	3.81	5.08	0.150	0.200
A ₁	0.38	1.27	0.015	0.050
B	0.38	0.51	0.015	0.020
B ₁	0.89	1.65	0.035	0.065
C	0.20	0.30	0.008	0.012
D	18.93	21.33	0.745	0.840
E	7.62	8.26	0.300	0.325
E ₁	5.59	7.11	0.220	0.280
e ₁	2.29	2.79	0.090	0.110
e _A	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
Q ₁	1.27	2.03	0.050	0.080
S	0.38	1.52	.015	0.060

ECN: S-03946—Rev. D, 09-Jul-01
DWG: 5482

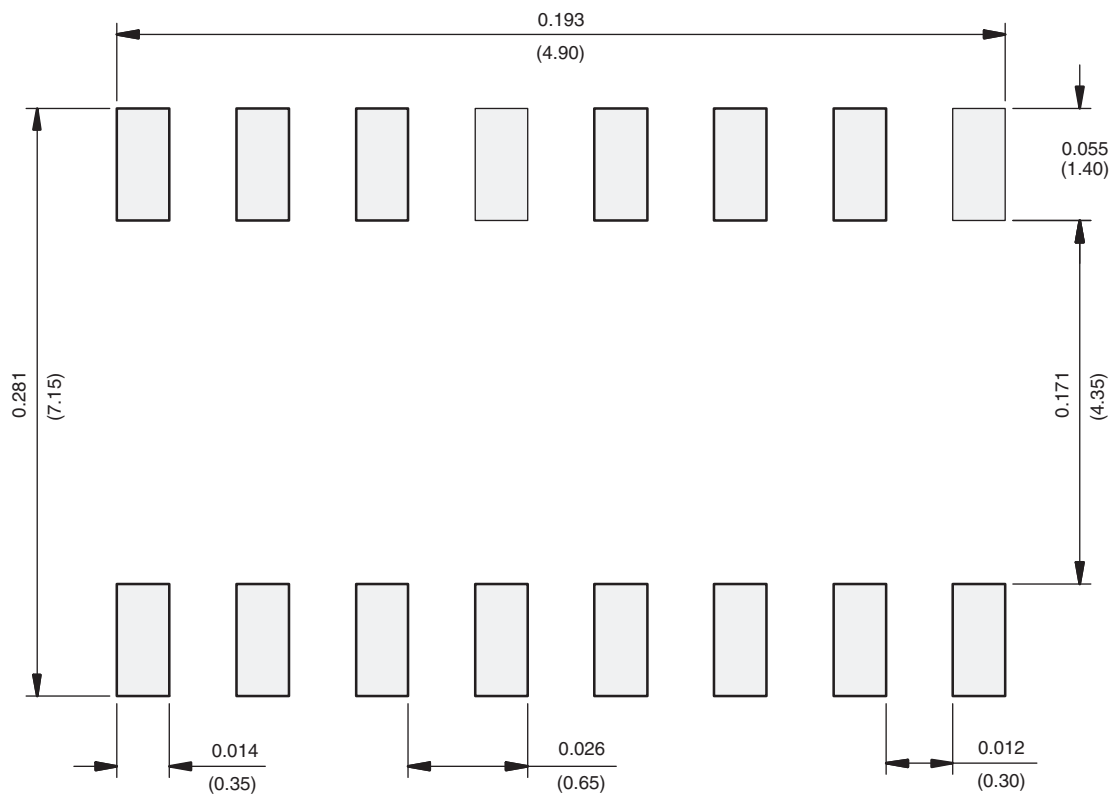
TSSOP: 16-LEAD



Symbols	DIMENSIONS IN MILLIMETERS		
	Min	Nom	Max
A	-	1.10	1.20
A1	0.05	0.10	0.15
A2	-	1.00	1.05
B	0.22	0.28	0.38
C	-	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
e	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
y	-	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D, 23-Oct-06			
DWG: 5624			



RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads
Dimensions in inches (mm)

RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads
Dimensions in Inches/(mm)

[Return to Index](#)



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.